MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Broduct data sheet









- 1. BASE
- 2. EMITTER
- 3. COLLECTOR

GC H!&' ...

TRANSISTOR (NPN)

: 95HI F9G

- For general AF applications
- High collector current
- High current gain
- Low collector-emitter saturation voltage
- Complementary types: BC807 (PNP)

7 @ GG= =75H=CB C: h_{FE'ff/k}

FUb_'	67,%+!%	67, %+!&) ·	67, %+!(\$
FUb[Y	%\$\$!&)\$"	% \$!(\$\$ [.]	&) \$!* \$\$ [.]
A Uf_]b[·	*5 [·]	*6`	*7`

MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	50	V
V _{CEO}	Collector-Emitter Voltage	45	V
V _{EBO}	Emitter-Base Voltage	5	V
Ic	Collector Current	500	mA
Pc	Collector Power Dissipation	300	mW
Roja	Thermal Resistance From Junction To Ambient	417	°C/W
T _J ,T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	℃

'9 @97 HF = 75 @7 < 5 F 57 H9 F = GH=7 G'fH≥1 &) °C'i b`Ygg'ch\Yfk]gY'gdYV]Z]YXŁ'

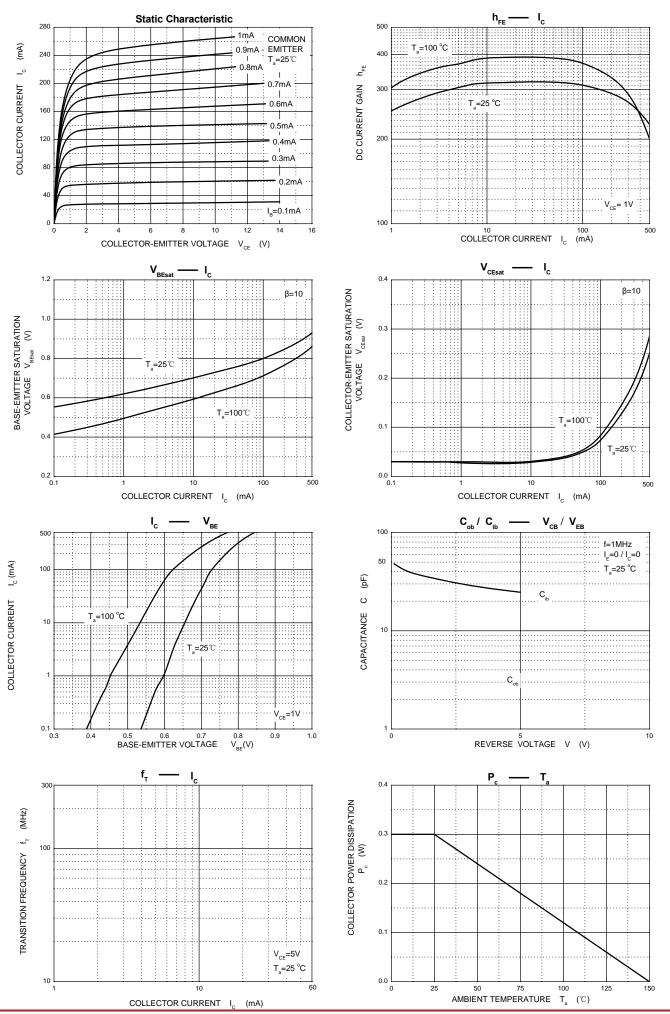
·····Dufua YhYf	'GmaVc`'	··· HYghi WcbX]hjcbgʻ	· Ain	Тур	. Aax	Unit
7 c``YWfcf!VUgY'VfYU_Xck b'j c`HU[Y'	V_{CBO}	I _C = 10μΑ, I _E =0	50			V
7 c``YWrcf!Ya]HhYf'VfYU_Xck b'j c`HU[Y'	V_{CEO}	I _C = 10mA, I _B =0	45			V
9a]hhYf!VUgY`VfYU_Xck b`j c`hU[Y`	V_{EBO}	I _E = 1μΑ, I _C =0	5			٧
7 c``YWrcf'WiHcZZWiffYbh	I _{CBO}	V _{CB} = 45 V , I _E =0			0.1	μA
9a]hhYf`WihcZZWiffYbh	I _{EBO}	V _{EB} = 4V, I _C =0			0.1	μA
87 W ffYbhi Ub	h _{FE(1)}	V _{CE} = 1V, I _C = 100mA	100		600	
or withing old	h _{FE(2)}	V _{CE} = 1V, I _C = 500mA	40			
7 c``YWrcf!Ya]lhYf`gUri fUr]cb'j c`lU[Y	V _{CE} (sat)	I _C = 500mA, I _B = 50mA			0.7	V
6 UgY!Ya]lhhYf 'gUhi fUh]cb 'j c`hU[Y	V _{BE} (sat)	I _C = 500mA, I _B = 50mA			1.2	V
6 UgY!Ya]HHYf'j c`HU[Y'	V_{BE}	V _{CE} = 1 V, I _C = 500mA			1.2	V
7 c``YWWf WUdUWJUbWY	C _{ob}	V _{CB} =10V ,f=1MHz		10		pF
Hfubg]hjcbʻZfYei YbWm	f⊤	V _{CE} = 5 V, I _C = 10mA f=100MHz	100			MHz



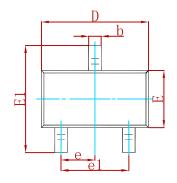


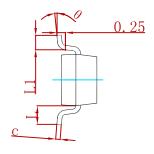


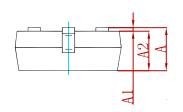
Typical Characteristics



PACKAGE MECHANICAL DATA

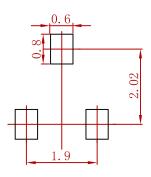






Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
Е	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022	2 REF	
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

Suggested Pad Layout



- 1.Controlling dimension:in millimeters.2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
BC817-16/25/40	SOT-23	3000



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